SN74LS283

4-Bit Binary Full Adder with Fast Carry

The SN74LS283 is a high-speed 4-Bit Binary Full Adder with internal carry lookahead. It accepts two 4-bit binary words (A_1–A_4, B_1–B_4) and a Carry Input (C_0). It generates the binary Sum outputs (Σ_1–Σ_4) and the Carry Output (C_4) from the most significant bit. The LS283 operates with either active HIGH or active LOW operands (positive or negative logic).

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	4.75	5.0	5.25	V
T_A	Operating Ambient Temperature Range	0	25	70	°C
I_{OH}	Output Current – High			–0.4	mA
I_{OL}	Output Current – Low			8.0	mA

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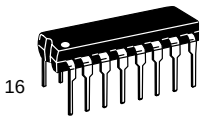
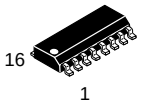
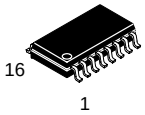
LOW POWER SCHOTTKY



PLASTIC
N SUFFIX
CASE 648



SOIC
D SUFFIX
CASE 751B



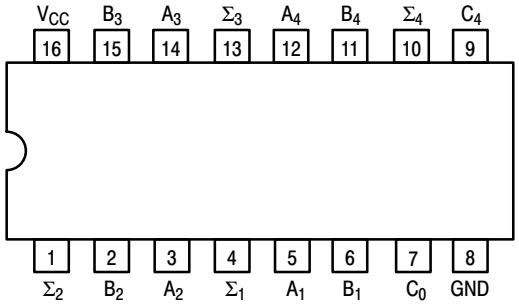
SOEIAJ
M SUFFIX
CASE 966

ORDERING INFORMATION

Device	Package	Shipping
SN74LS283N	16 Pin DIP	2000 Units/Box
SN74LS283D	SOIC–16	38 Units/Rail
SN74LS283DR2	SOIC–16	2500/Tape & Reel
SN74LS283M	SOEIAJ–16	See Note 1
SN74LS283MEL	SOEIAJ–16	See Note 1

1. For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

CONNECTION DIAGRAM DIP (TOP VIEW)

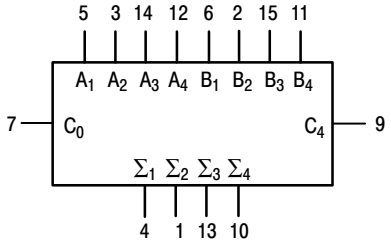


NOTE:
The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

PIN NAMES		LOADING (Note a) HIGH	LOW
$A_1 - A_4$	Operand A Inputs	1.0 U.L.	0.5 U.L.
$B_1 - B_4$	Operand B Inputs	1.0 U.L.	0.5 U.L.
C_0	Carry Input	0.5 U.L.	0.25 U.L.
$\Sigma_1 - \Sigma_4$	Sum Outputs	10 U.L.	5 U.L.
C_4	Carry Output	10 U.L.	5 U.L.

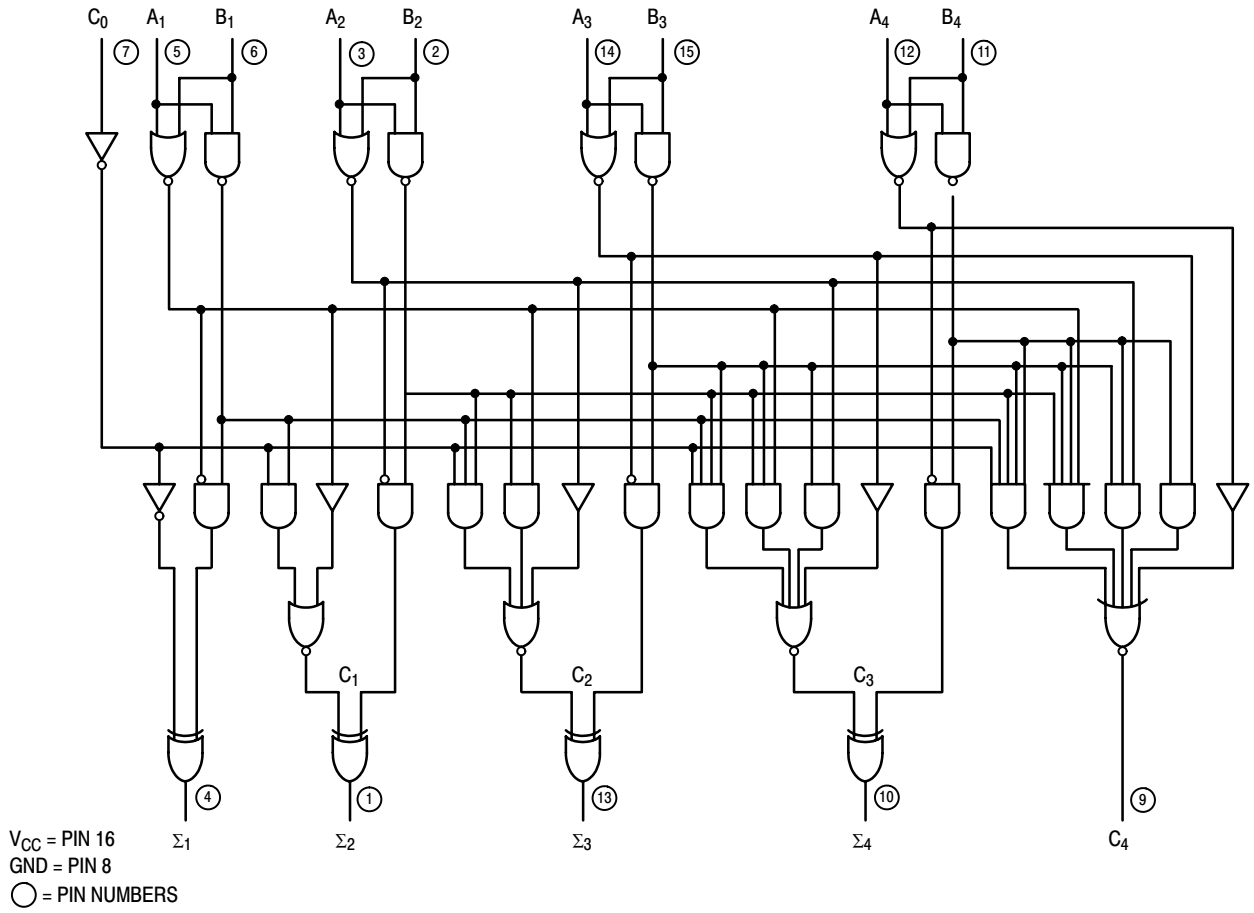
NOTES:
a) 1 TTL Unit Load (U.L.) = 40 μA HIGH/1.6 mA LOW.

LOGIC SYMBOL



V_{CC} = PIN 16
GND = PIN 8

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS283 adds two 4-bit binary words (A plus B) plus the incoming carry. The binary sum appears on the sum outputs (Σ_1–Σ_4) and outgoing carry (C4) outputs.

$C_0 + (A_1 + B_1) + 2(A_2 + B_2) + 4(A_3 + B_3) + 8(A_4 + B_4) = \Sigma_1 + 2\Sigma_2 + 4\Sigma_3 + 8\Sigma_4 + 16C_4$

Where: (+) = plus

Due to the symmetry of the binary add function the LS283 can be used with either all inputs and outputs active HIGH (positive logic) or with all inputs and outputs active LOW (negative logic). Note that with active HIGH inputs, Carry Input can not be left open, but must be held LOW when no carry in is intended.

Example:

	C_0	A_1	A_2	A_3	A_4	B_1	B_2	B_3	B_4	Σ_1	Σ_2	Σ_3	Σ_4	C_4	
logic levels	L	L	H	L	H	H	L	L	H	H	H	L	L	H	
Active HIGH	0	0	1	0	1	1	0	0	1	1	1	0	0	1	(10+9=19)
Active LOW	1	1	0	1	0	0	1	1	0	0	0	1	1	0	(carry+5+6=12)

Interchanging inputs of equal weight does not affect the operation, thus C_0, A_1, B_1, can be arbitrarily assigned to pins 7, 5 or 3.

FUNCTIONAL TRUTH TABLE

C (n–1)	A_n	B_n	Σ_n	C_n
L	L	L	L	L
L	L	H	H	L
L	H	L	H	L
L	H	H	L	H
H	L	L	H	L
H	L	H	L	H
H	H	L	L	H
H	H	H	H	H

C_1–C_3 are generated internally
C_0 is an external input
C_4 is an output generated internally

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter		Limits Min	Limits Typ	Limits Max	Unit	Test Conditions	
V_{IH}	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V_{IL}	Input LOW Voltage				0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V_{IK}	Input Clamp Diode Voltage			–0.65	–1.5	V	V_{CC} = MIN, I_{IN} = –18 mA	
V_{OH}	Output HIGH Voltage		2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
V_{OL}	Output LOW Voltage			0.25	0.4	V	I_{OL} = 4.0 mA	V_{CC} = V_{CC} MIN, V_{IN} = V_{IL} or V_{IH} per Truth Table
				0.35	0.5	V	I_{OL} = 8.0 mA	
I_{IH}	Input HIGH Current	C_0			20	μA	V_{CC} = MAX, V_{IN} = 2.7 V	
		Any A or B			40	μA		
		C_0			0.1	mA	V_{CC} = MAX, V_{IN} = 7.0 V	
		Any A or B			0.2	mA		
I_{IL}	Input LOW Current	C_0			–0.4	mA	V_{CC} = MAX, V_{IN} = 0.4 V	
		Any A or B			–0.8	mA		
I_{OS}	Short Circuit Current (Note 1)		–20		–100	mA	V_{CC} = MAX	
I_{CC}	Power Supply Current Total, Output HIGH				34	mA	V_{CC} = MAX	
	Total, Output LOW				39			

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

Symbol	Parameter	Limits			Unit	Test Conditions
		Min	Typ	Max		
t_{PLH} t_{PHL}	Propagation Delay, C_0 Input to Any Σ Output		16 15	24 24	ns	C_L = 15 pF Figures 1 & 2
t_{PLH} t_{PHL}	Propagation Delay, Any A or B Input to Σ Outputs		15 15	24 24	ns	
t_{PLH} t_{PHL}	Propagation Delay, C_0 Input to C_4 Output		11 11	17 22	ns	
t_{PLH} t_{PHL}	Propagation Delay, Any A or B Input to C_4 Output		11 12	17 17	ns	

AC WAVEFORMS

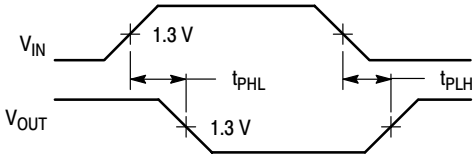


Figure 1.

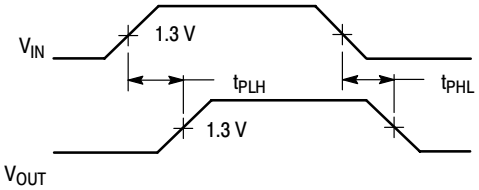
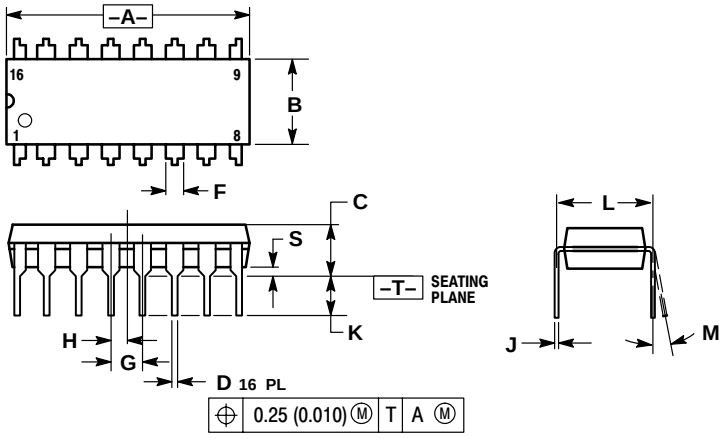


Figure 2.

PACKAGE DIMENSIONS

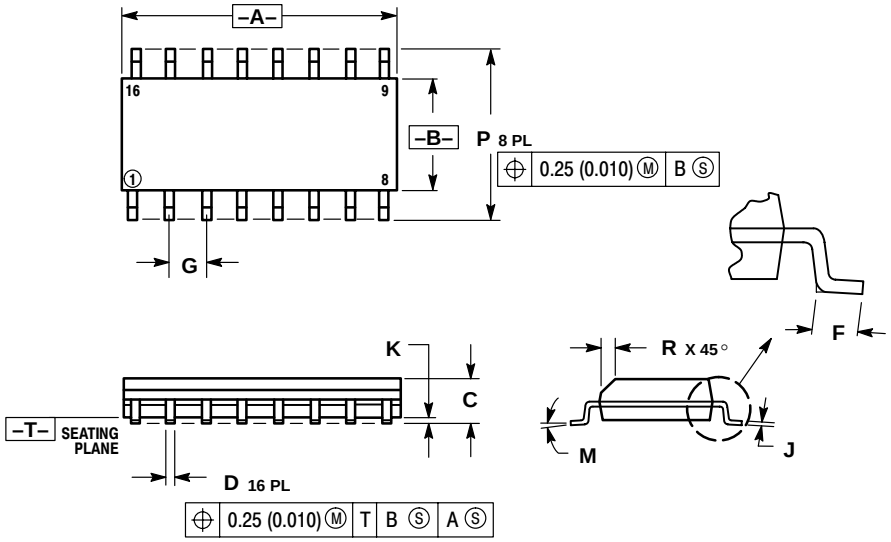
N SUFFIX
PLASTIC PACKAGE
CASE 648–08
ISSUE R



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751B–05
ISSUE J

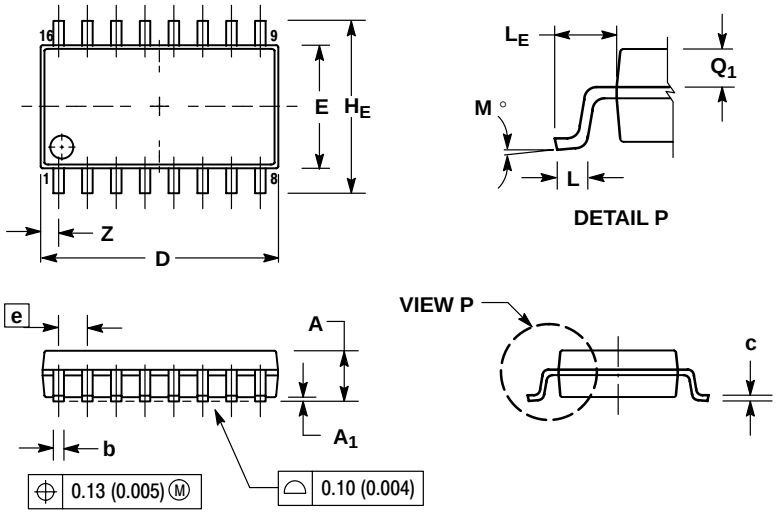


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

PACKAGE DIMENSIONS

M SUFFIX
SOEIAJ PACKAGE
CASE 966–01
ISSUE O



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A_1	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H_E	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L_E	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q_1	0.70	0.90	0.028	0.035
Z	---	0.78	---	0.031

PUBLICATION ORDERING INFORMATION

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